

ESD3V3D5

Description

ESD3V3D5 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

Features

- Uni-directional ESD protection of one line
- Package: SOD-523
- Ultra low leakage
- Low operating voltage:3.3V
- Low clamping voltage

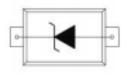
Absolute Ratings

- Response Time is Typically < 1 ns</p>
- Complies with following standards:
- IEC 61000-4-2 (ESD) immunity test Air discharge: ±30kV
 - Contact discharge: ±30kV
- IEC61000-4-5 (Lightning) 20A (8/20µs)

Applications

- Computers and peripherals
- Digital Cameras
- Audio and video equipment
- Cellular handsets and accessories
- Other electronics equipments communication systems.

Circuit Diagram



Tamb=25°C unless otherwise specified			
Parameter	Symbol	Value	Unit
Peak pulse power (tp = 8/20µs)	Рек	300	W
Maximum Reverse Peak Pulse Current(8/20µS)	Ірр	20	А
ESD per IEC 61000-4-2 (Air)		±30	KV
ESD per IEC 61000-4-2 (Contact)	Vesd	±30	ΓV
Storage Temperature Range	T _{STJ}	-55 to +150	°C
Operating Temperature Range	TJ	-55 to +125	°C

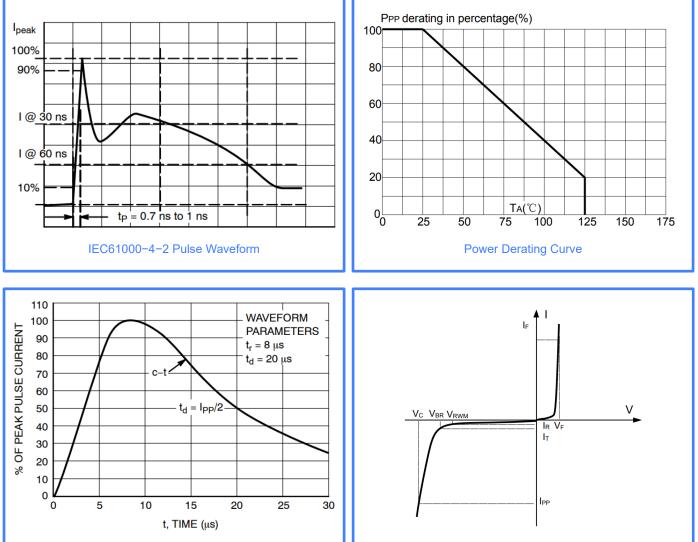
Electrical Characteristics

TA=25°C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{RWM}	Reverse Working Peak Voltage	-			3.3	V
V _{BR}	Reverse Breakdown Voltage	IT = 1mA	5		7	V
IR	Reverse Current	V _{RWM} =3.3V			0.5	μA
Vc	Clamping Voltage	I _{PP} =20A, t _P =8/20µs			15	V
CD	Diode Capacitance	VR = 0V, f = 1MHz			200	pF



TVS DIODE ESD3V3D5

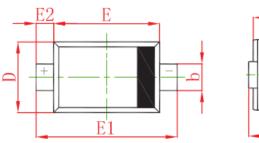


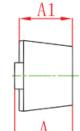
8/20µs Pulse Waveform

V-I Characteristics for Unidirectional Diode



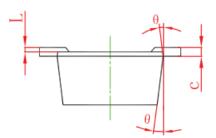
SOD523 Package Outline & Dimensions

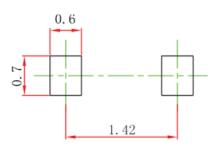




Symbol	Dimensions in mm		
Symbol	min	max	
А	0.530	0.730	
A1	0.500	0.700	
b	0.280	0.380	
с	0.080	0.150	
D	0.750	0.850	
E	1.100	1.300	
E1	1.500	1.700	
E2	0.200REF		
L	0.010	0.070	
θ	7° REF		

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Pad Layout

Disclaimer

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.

Users should verify actual device performance in their specific applications.